MMBTA42LT1, MMBTA43LT1

MMBTA42LT1 is a Preferred Device

High Voltage Transistors NPN Silicon

Features

• Pb–Free Package May be Available. The G–Suffix Denotes a Pb–Free Lead Finish

MAXIMUM RATINGS

Rating	Symbol	MMBTA42	MMBTA43	Unit
Collector-Emitter Voltage	V _{CEO}	300	200	Vdc
Collector-Base Voltage	V _{CBO}	300	200	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	6.0	Vdc
Collector Current–Continuous	I _C	500		mAdc

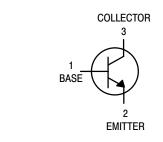
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1)	P _D	225	mW
T _A = 25°C Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C	P _D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



http://onsemi.com





SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAMS





MMBTA42LT1

MMBTA43LT1

1D, M1E = Specific Device Code X = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]	
MMBTA42LT1	SOT-23	3000/Tape & Reel	
MMBTA42LT1G	SOT-23	3000/Tape & Reel	
MMBTA43LT1	SOT-23	3000/Tape & Reel	
MMBTA43LT3	SOT-23	10000/Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MMBTA42LT1, MMBTA43LT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 3) (I _C = 1.0 mAdc, I _B = 0)	MMBTA42 MMBTA43	V _(BR) CEO	300 200	_ _	Vdc
Collector – Base Breakdown Voltage ($I_C = 100 \mu Adc, I_E = 0$)	MMBTA42 MMBTA43	V _(BR) CBO	300 200	- -	Vdc
Emitter – Base Breakdown Voltage ($I_E = 100 \mu Adc, I_C = 0$)		V _{(BR)EBO}	6.0	-	Vdc
Collector Cutoff Current $(V_{CB} = 200 \text{ Vdc}, I_{E} = 0)$ $(V_{CB} = 160 \text{ Vdc}, I_{E} = 0)$	MMBTA42 MMBTA43	I _{CBO}	- -	0.1 0.1	μAdc
Emitter Cutoff Current $(V_{EB} = 6.0 \text{ Vdc}, I_{C} = 0)$ $(V_{EB} = 4.0 \text{ Vdc}, I_{C} = 0)$	MMBTA42 MMBTA43	I _{EBO}	- -	0.1 0.1	μAdc
ON CHARACTERISTICS (Note 3)					
DC Current Gain ($I_C = 1.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$)	Both Types Both Types	h _{FE}	25 40	_ _	_
$(I_C = 30 \text{ mAdc}, V_{CE} = 10 \text{ Vdc})$	MMBTA42 MMBTA43		40 40	- -	
Collector – Emitter Saturation Voltage (I _C = 20 mAdc, I _B = 2.0 mAdc)	MMBTA42 MMBTA43	V _{CE(sat)}	- -	0.5 0.5	Vdc
Base–Emitter Saturation Voltage ($I_C = 20 \text{ mAdc}$, $I_B = 2.0 \text{ mAdc}$)		V _{BE(sat)}	-	0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS		· · · · · ·			
Current – Gain – Bandwidth Product (I _C = 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)		f⊤	50	_	MHz
Collector-Base Capacitance $(V_{CB} = 20 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	MMBTA42 MMBTA43	C _{cb}	- -	3.0 4.0	pF

^{3.} Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

MMBTA42LT1, MMBTA43LT1

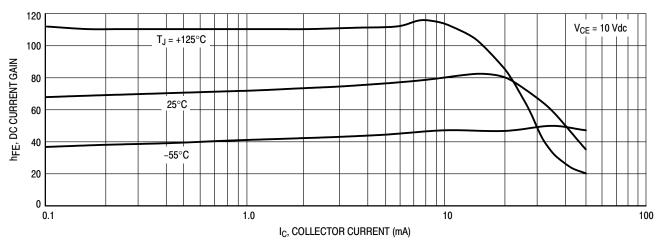


Figure 1. DC Current Gain

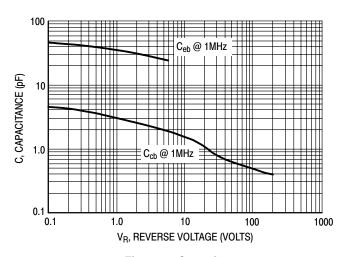


Figure 2. Capacitance

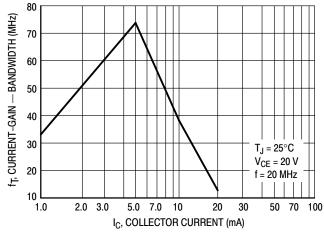


Figure 3. Current-Gain - Bandwidth

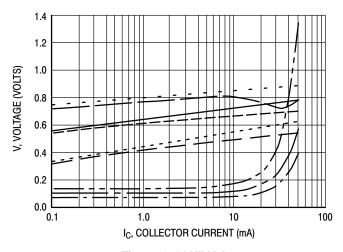
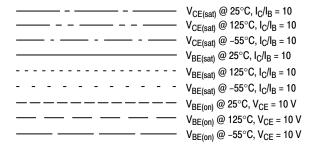


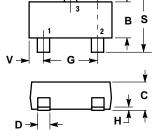
Figure 4. "ON" Voltages



MMBTA42LT1, MMBTA43LT1

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AH**





- DIMENSIONING AND TOLERANCING PER ANSI
- DIMENSIONING AND TOLERANGING FED AND 1942.
 Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
Н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
٧	0.0177	0.0236	0.45	0.60

STYLE 6:

BASE PIN 1.

- **EMITTER**
- 3. COLLECTOR

SOLDERING FOOTPRINT*

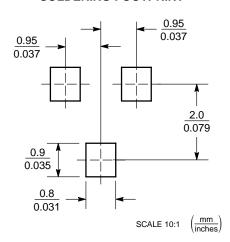


Figure 5. SOT-23

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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